



VHS VCR Playback Head and Record Amplifiers

Overview

The LA7415 is a record and playback amplifier IC for VHS format VCR decks. In combination with a Sanyo LC7420 or LA7430 Series video signal processing IC, the LA7415 can provide an adjustment-free Y/C record current.

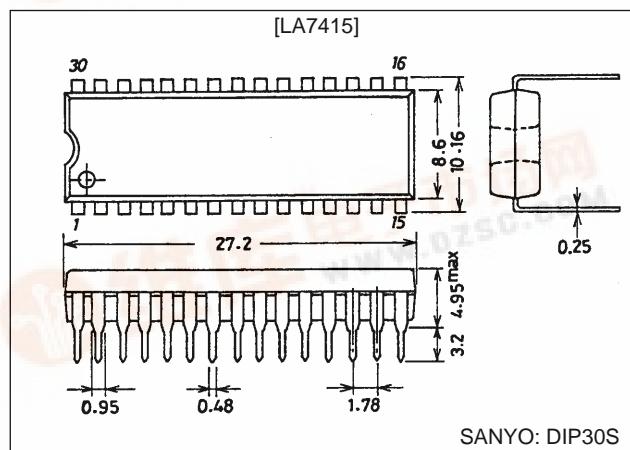
Features

- Record amplifier: Provides stable recording characteristics using a fixed-current drive technique that is resistant to load variations.
- REC-AMP: Includes a built-in AGC circuit.
- Can use the same printed circuit board as the LA7411.

Package Dimension

unit: mm

3061-DIP30S



Specifications

Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V _{CC} max		7.0	V
Allowable power dissipation	P _d max	T _a 65 °C	650	W
Operating temperature	T _{opr}		-10 to +65	°C
Storage temperature	T _{stg}		-40 to +150	°C

Operating Conditions at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage	V _{CC}		5.0	V
Operating voltage range	V _{CCop}		4.8 to 5.5	V

Electrical Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol			Conditions				Ratings			Unit	
		Input	Output		T2	T4	T5	min	typ	max		
[Playback Mode]				T15: 5.0 V, T13: OPEN, T7: OPEN		TRCK	HA	SW30 MUTE				
Current drain	I _{CCP}			Pin 15 influx current	OPEN	0	0	24	30	36	mA	
Voltage gain	SP L CH1	V _{Gp1}	T20A	T10A	$V_{IN} = 38 \text{ mVp-p}, f = 1 \text{ MHz}$	OPEN	0	0	54.0	57.0	60.0 dB	
	SP H CH2	V _{Gp2}	T23A	T10A		OPEN	0	2.5	54.0	57.0	60.0 dB	
	EP L CH3	V _{Gp3}	T27A	T10A		OPEN	5.0	0	56.0	59.0	62.0 dB	
	EP H CH4	V _{Gp4}	T30A	T10A		OPEN	5.0	2.5	56.0	59.0	62.0 dB	
Voltage gain differential 1	V _{G p1}	-	-	V _{Gp1} - V _{Gp2}	-	-	-	-1	0	+1	dB	
Voltage gain differential 2	V _{G p2}	-	-	V _{Gp3} - V _{Gp4}	-	-	-	-1	0	+1	dB	
Inter-mode gain difference	V _{Gp EP-SP}	-	-	V _{Gp3} - V _{Gp1}	-	-	-	1	2	3	dB	
Equivalent input noise voltage	CH1	V _{NIN1}	T20A	T10A	After the 1.1-MHz LPF $\frac{V_{OUT}}{V_{Gp1, 2, 3, 4}}$	OPEN	0	0	-	1.1	1.5 μVRms	
	CH2	V _{NIN2}	T23A	T10A		OPEN	0	2.5	-	1.1	1.5 μVRms	
	CH3	V _{NIN3}	T27A	T10A		OPEN	5.0	0	-	1.1	1.5 μVRms	
	CH4	V _{NIN4}	T30A	T10A		OPEN	5.0	2.5	-	1.1	1.5 μVRms	
Frequency characteristics	CH1	V _{f p1}	T20A	T10A	$V_{IN} = 38 \text{ mVp-p}, f = 7 \text{ MHz}$ $\frac{V_{OUT}}{V_{Gp1, 2, 3, 4}}$ output ratio	OPEN	0	0	-2.5	0	-	dB
	CH2	V _{f p2}	T23A	T10A		OPEN	0	2.5	-2.5	0	-	dB
	CH3	V _{f p3}	T27A	T10A		OPEN	5.0	0	-2.5	0	-	dB
	CH4	V _{f p4}	T30A	T10A		OPEN	5.0	2.5	-2.5	0	-	dB
Second harmonic distortion	CH1	V _{HDP1}	T20A	T10A	$V_{IN} = 38 \text{ mVp-p}, f = 4 \text{ MHz}$ (8-MHz component)/(4-MHz component) output ratio	OPEN	0	0	-	-40	-35	dB
	CH2	V _{HDP2}	T23A	T10A		OPEN	0	2.5	-	-40	-35	dB
	CH3	V _{HDP3}	T27A	T10A		OPEN	5.0	0	-	-40	-35	dB
	CH4	V _{HDP4}	T30A	T10A		OPEN	5.0	2.5	-	-40	-35	dB
Maximum output level	CH1	V _{OMP1}	T20A	T10A	$f = 1 \text{ MHz}$ The output level when the third harmonic in the output is -30 dB	OPEN	0	0	1.0	1.2	-	V _{p-p}
	CH2	V _{OMP2}	T23A	T10A		OPEN	0	2.5	1.0	1.2	-	V _{p-p}
	CH3	V _{OMP3}	T27A	T10A		OPEN	5.0	0	1.0	1.2	-	V _{p-p}
	CH4	V _{OMP4}	T30A	T10A		OPEN	5.0	2.5	1.0	1.2	-	V _{p-p}
Crosstalk SP (Note 1)	CH1	V _{CR1}	T23A	T10A	$V_{IN} = 38 \text{ mVp-p}, f = 4 \text{ MHz}$ $\frac{V_{OUT}}{V_{Gp1, 2}}$	OPEN	0	0	-	-40	-35	dB
			T27A	T10A		OPEN	0	0	-	-40	-35	dB
			T30A	T10A		OPEN	0	0	-	-40	-35	dB
	CH2	V _{CR2}	T20A	T10A		OPEN	0	2.5	-	-40	-35	dB
			T27A	T10A		OPEN	0	2.5	-	-40	-35	dB
			T30A	T10A		OPEN	0	2.5	-	-40	-35	dB
Crosstalk EP (Note 1)	CH3	V _{CR3}	T23A	T10A	$V_I = 38 \text{ mVp-p}, f = 4 \text{ MHz}$ $\frac{V_{OUT}}{V_{Gp3, 4}}$	OPEN	5.0	0	-	-40	-35	dB
			T27A	T10A		OPEN	5.0	0	-	-40	-35	dB
			T30A	T10A		OPEN	5.0	0	-	-40	-35	dB
	CH4	V _{CR4}	T20A	T10A		OPEN	5.0	2.5	-	-40	-35	dB
			T27A	T10A		OPEN	5.0	2.5	-	-40	-35	dB
			T30A	T10A		OPEN	5.0	2.5	-	-40	-35	dB
Output DC offset	V _{ODC1}	-	T10	CH1-CH2		OPEN	-	0	-100	0	+100	mV
			T10	CH3-CH4		OPEN	0	2.5	-100	0	+100	mV
			T10	CH1-CH3		OPEN	-	0	-100	0	+100	mV
			T10	CH2-CH4		OPEN	5.0	2.5	-100	0	+100	mV
			T10	CH1-CH4		OPEN	0	-	-100	0	+100	mV
			T10	CH2-CH3		OPEN	5.0	2.5	-100	0	+100	mV
	V _{ODC2}	-	T10	CH1-CH2		OPEN	0	2.5	-100	0	+100	mV
			T10	CH3-CH4		OPEN	-	0	-100	0	+100	mV
			T10	CH1-CH3		OPEN	5.0	0	-100	0	+100	mV
			T10	CH2-CH4		OPEN	0	-	-100	0	+100	mV
			T10	CH1-CH4		OPEN	5.0	2.5	-100	0	+100	mV
			T10	CH2-CH3		OPEN	0	2.5	-100	0	+100	mV

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Note 1. With the input inductor L (8.2 μH) shorted.

2. Since the T4 (HA) control switch timing is synchronized with T6 (H-Sync), a T6 trigger (0 - 5 V - 0) must be input before measuring each of these items.

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Parameter	Symbol			Conditions				Ratings			Unit
		Input	Output		T2	T4	T5	min	typ	max	
						TRCK	HA	SW30 MUTE			
Enveloped detector output pin voltage	V _{ENV}		T8	The T8 DC voltage with no input	OPEN	0	0	0	0.4	0.8	V
Enveloped detector voltage SP1	V _{ENVSP1}	T20A	T8	f = 4 MHz T10A: Adjusted to 300 mV p-p	OPEN	0	0	2.1	2.6	3.1	V
Enveloped detector voltage SP2	V _{ENVSP2}	T20A	T8	f = 4 MHz T10A: Adjusted to 600 mV p-p	OPEN	0	0	4.5	4.8	5.0	V
Enveloped detector voltage EP1	V _{ENVEP1}	T27A	T8	f = 4 MHz T10A: Adjusted to 200 mV p-p	OPEN	5.0	0	2.0	2.6	3.0	V
Enveloped detector voltage EP2	V _{ENVEP2}	T27A	T8	f = 4 MHz T10A: Adjusted to 450 mV p-p	OPEN	5.0	0	4.5	4.8	5.0	V
Comparator output voltage 1	V _{COMP1}	T20A	T3	f = 4 MHz, V _{IN} = 38 mVp-p The T3 DC voltage	5.0	0	0	-	0.4	0.7	V
Comparator output voltage 2	V _{COMP2}	T20A	T3	f = 4 MHz, V _{IN} = 38 mVp-p The T3 DC voltage	5.0	5.0	0	4.5	4.8	-	V
Playback mode on switching transistor on resistance	R _{PON17}		P-17	The difference in the DC measurement for 1-mA and 2-mA influx currents	-	-	-	-	4.0	6.0	
	R _{PON18}		P-18		-	-	-	-	4.0	6.0	
Playback mode mode switching transistor on resistance	R _{PON21}		P-21	The difference in the DC measurement for 1-mA and 2-mA influx currents	OPEN	5.0	-	-	4.0	6.0	
	R _{PON24}		P-24		OPEN	5.0	-	-	4.0	6.0	
	R _{PON26}		P-26		OPEN	0	-	-	4.0	6.0	
	R _{PON29}		P-29		OPEN	0	-	-	4.0	6.0	
Trick 1 threshold level	TR1-1		T2	Normal → Trick1	*	-	-	3.2	-	5.0	V
	TR1-2		T2	Trick1 → Normal	*	-	-	1.2	-	2.8	V
Trick 2 threshold level	TR2-1		T2	Normal → Trick2	*	-	-	0.0	-	0.8	V
	TR2-2		T2	Trick2 → Normal	*	-	-	1.2	-	2.8	V
HAPB threshold level	HAP-1		T4	SP → EP	-	*	-	1.8	-	5.0	V
	HAP-2		T4	EP → SP	-	*	-	0.0	-	1.4	V
SW30 threshold level	SW30-1		T5	Lch → Hch	-	-	*	1.2	-	5.0	V
	SW30-2		T4	Hch → Lch	-	-	*	0.0	-	0.8	V
					T2	T4	T5				
[Record Mode]				T15: 5.0 V, T2: OPEN, T6: 5.0 V, T7: 5.0 V	REC Adj2	HA	SW30 MUTE				
Current drain	I _{ICCR}			The pin 15 influx current	OPEN	0	0	44	55	66	mA
AGC amplifier output level	V _{RSP}	T11A	T21A	f = 4 MHz V _{IN} = 200 mVp-p	OPEN	0	0	147	156	165	mVp-p
	V _{REP}	T11A	T26A		OPEN	5.0	0	116	123	130	mVp-p
Inter-mode gain difference	V _{G R}	-	-	V _{RSP} /V _{REP}	-	-	-	1.30	2.05	2.80	dB
AGC amplifier control characteristics 1	V _{AGC1-SP}	T11A	T21A	f = 4 MHz, V _{IN} = 400 mVp-p The output level/V _{RSP} , EP ratio	OPEN	0	0	-	0.5	1.0	dB
	V _{AGC1-EP}	T11A	T26A		OPEN	5.0	0	-	0.5	1.0	dB
AGC amplifier control characteristics 2	V _{AGC2-SP}	T11A	T21A	f = 4 MHz, V _{IN} = 100 mVp-p The output level/V _{RSP} , EP ratio	OPEN	0	0	-1.0	-0.5	-	dB
	V _{AGC2-EP}	T11A	T26A		OPEN	5.0	0	-1.0	-0.5	-	dB
AGC amplifier frequency characteristics	V _{F RS}	T11A	T21A	f = 1 MHz, 7 MHz, V _{IN} = 100 mVp-p The 7 MHz/1 MHz output ratio	OPEN	0	0	-1.0	-0.0	+1.0	dB
	V _{F RE}	T11A	T26A		OPEN	5.0	0	-1.0	-0.0	+1.0	dB
AGC amplifier second harmonic distortion	V _{HDRS}	T11A	T21A	f = 4 MHz, V _{IN} = 200 mVp-p The (8 MHz component)/(4 MHz component) output ratio	OPEN	0	0	-	-45	-40	dB
	V _{HDRE}	T11A	T21A		OPEN	5.0	0	-	-45	-40	dB
AGC amplifier maximum output level	V _{OMRS}	T11A	T21A	f = 4 MHz, The output level for which the second harmonic is -35 dB	Adj.	0	0	20	22	-	mAp-p
	V _{OMRE}	T11A	T26A		Adj.	5.0	0	20	22	-	mAp-p
AGC amplifier muting attenuation	V _{MRS}	T11A	T21A	f = 4 MHz, VI = 200 mVp-p The output level/V _{RSP} , EP ratio	OPEN	0	5.0	-	-45	-40	dB
	V _{MRE}	T11A	T26A		OPEN	5.0	5.0	-	-45	-40	dB

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Parameter	Symbol			Conditions				Ratings			Unit
		Input	Output		T2	T4	T5	min	typ	max	
[Record Mode]				T15: 5.0 V, T2: OPEN, T6: 5.0 V, T7: 5.0 V	REC Adj2	HA	SW30 MUTE				
AGC amplifier relative cross modulation level	V _{CYS}	T10A	T21A	T10A: f = 629 kHz, V _{IN} = 360 mVp-p T11A: f = 4 MHz, V _{IN} = 200 mVp-p (4 MHz ±629 kHz)/(4 MHz) output ratio	OPEN	0	0	—	-45	-40	dB
	V _{CYE}	T11A	T26A		OPEN	5.0	0	—	-45	-40	dB
Record mode mode switching transistor on resistance	R _{RON17}		P-17	The difference in the DC measurement for 1-mA and 2-mA influx currents	OPEN	5.0	—	—	4.0	6.0	
	R _{RON18}		P-18		OPEN	0	—	—	4.0	6.0	
	R _{RON21}		P-21		OPEN	5.0	—	—	4.0	6.0	
	R _{RON24}		P-24		OPEN	5.0	—	—	4.0	6.0	
	R _{RON26}		P-26		OPEN	0	—	—	4.0	6.0	
	R _{RON29}		P-29		OPEN	0	—	—	4.0	6.0	
HA record threshold level	HAR-1		T4	SP → EP	—	*	—	1.8	—	5.0	V
	HAR-2		T4	EP → SP	—	*	—	0.0	—	1.4	V
Record MUTE threshold level	MUTE-1		T5	MUTE OFF → ON	—	—	*	3.4	—	5.0	V
	MUTE-2		T5	MUTE ON → OFF	—	—	*	0.0	—	3.0	V
Record/playback threshold level	SW REC/PB			T7: control voltage	—	—	—	2.2	—	5.0	V

Notes 3. Measure with a DC voltage of about 1.8 V applied to the AGC detector filter pin (pin 12) and with the AGC amplifier gain fixed.

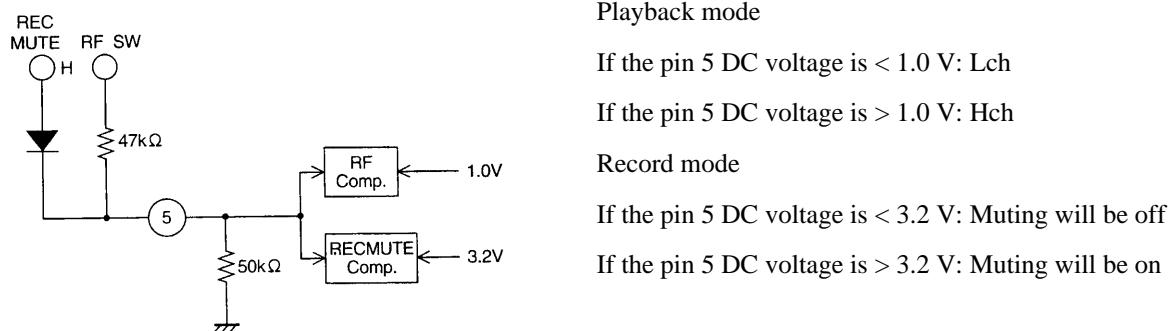
4. Adjust the output level by applying a DC voltage to T13 (REC CUR.Adj2)

5. Use a resistor with a ±1.0% tolerance between pins 14 and 15.

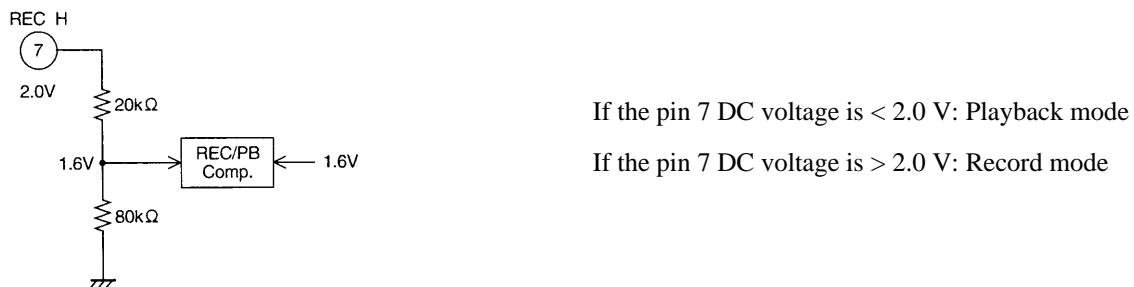
Usage Notes

1. Control Pin Logic

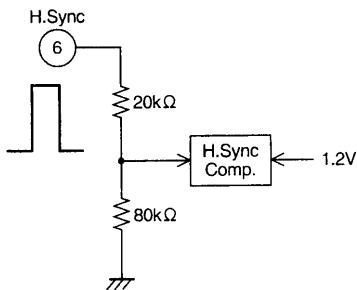
RF SW, REC MUTE: pin 5



Record/playback mode switching: pin 7



H.Sync input: pin 6

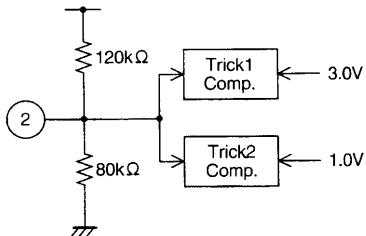


If the pin 6 DC voltage is > 1.5 V: Currently the signal is in an H.Sync period

*: Playback mode: Used for switching timing in SP search.

Record mode: Used as the record amplifier AGC synchronization block gate pulse.

(4) Playback trick mode switching: pin 2



If the pin 2 DC voltage is > 3.0 V: Trick 1

If the pin 2 DC voltage is < 1.0 V: Trick 2

If the pin 2 DC voltage is > 1.0 V and < 3.0 V: Normal

*: Normal mode: Two channels controlled (EP/SP) by pin 4: ON

Envelope comparator: OFF

In trick 1 and 2 modes: All 4 channels: ON

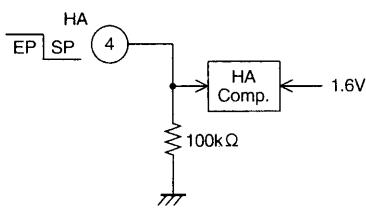
Envelope comparator: ON

*: The difference between trick 1 and trick 2 is that:

Trick1 Envelope comparator (pin 3) output → Servo (microcontroller) or
 → Pin 4 HA → SP search is performed in the HA switch path.

Trick2 Envelope comparator output → SP search is performed in the HA switch path. (See the block diagram.)

HA SW (EP/SP mode switching): pin 4

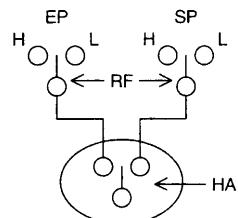


If the pin 4 DC voltage is < 1.6 V: SP mode

If the pin 4 DC voltage is > 1.6 V: EP mode

*: H.Sync synchronization for HA switching:

The switching of the HA SW circuit shown in the figure at the right is synchronized with the H.Sync signal input to pin 6.
 (Other EP/SP switching is performed in real time.)



Comp.OUT (pin 3)

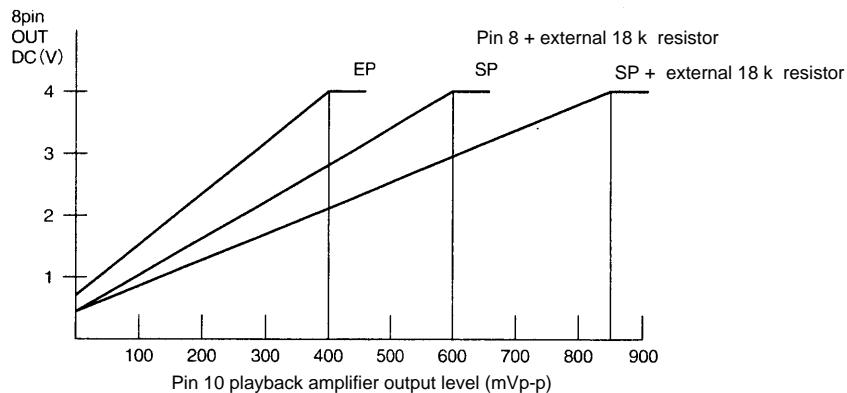
If the EP envelope is > SP: High (4.0 V or higher)

If the EP envelope is < SP: Low (0.7 V or lower)

2. Envelope Detector Characteristics: pin 8

The LA6529M includes an on-chip playback signal envelope detector circuit used to achieve automatic tracking adjustment with essentially linear characteristics.

Envelope Detector Characteristics (design target values) $f = 4 \text{ MHz}$

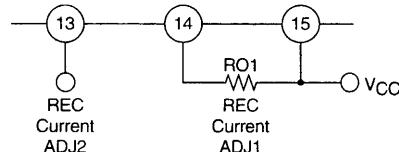


3. Record Amplifier Gain Control

The LA6529M achieves an adjustment-free record current by adding an AGC circuit in the record amplifier block. The record current can be modified using the circuit shown below.

(1) REC Current.Adj2: When open

The pin 13 DC level is set to $1/2 V_{CC}$ (about 2.5 V) by an internal bias and the record current is determined by RO1.



Design values: RO1: $1.5 \text{ k} = 15.6 \text{ mA}\text{p-p}$ (SP) (per channel)
 $= 12.3 \text{ mA}\text{p-p}$ (EP)

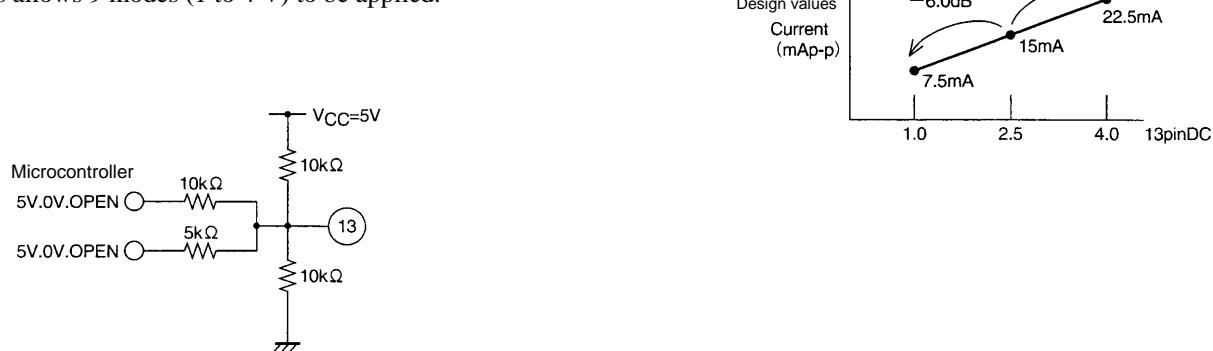
(2) REC Current.Adj2: When used

The value determined by RO1 can be adjusted from -6.0 dB to $+3.5 \text{ dB}$ by applying a control DC level (1 to 4 V) to pin 13.

(Reference)

The circuit below can be used to apply the DC control level to pin 13.

This allows 9 modes (1 to 4 V) to be applied.



Pin Functions

Pin No.	Pin	Standard DC voltage (V)	Pin circuit	Notes				
1 19 22 28	PB Amp Second filter	PB REC	2.0 3.6					
2	TRICK-H			<p>3.0 V 1.0 V</p> <table border="1"> <tr><td>Trick1</td></tr> <tr><td>NORMAL</td></tr> <tr><td>Trick2</td></tr> </table>	Trick1	NORMAL	Trick2	
Trick1								
NORMAL								
Trick2								
3	COMP-OUT	PB REC	High: 4.5 V or higher Low: 0.7 V or lower OPEN	<p>EP > SP ENV: High</p>				
4	HA (EP/SP)			<p>1.6 V</p> <table border="1"> <tr><td>EP</td></tr> <tr><td>SP</td></tr> </table>	EP	SP		
EP								
SP								
5	RF-SW (REC-MUTE)			<p>SW30 REC MUTE</p> <table border="1"> <tr><td>Hch</td></tr> <tr><td>ON</td></tr> <tr><td>OFF</td></tr> </table> <p>1.0 (V)</p> <table border="1"> <tr><td>Lch</td></tr> </table>	Hch	ON	OFF	Lch
Hch								
ON								
OFF								
Lch								
6	H-SYNC			<p>Sync H L</p> <p>1.5 V</p>				

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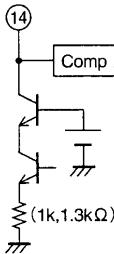
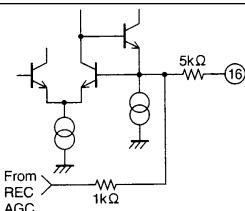
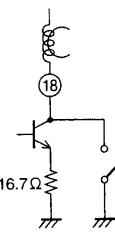
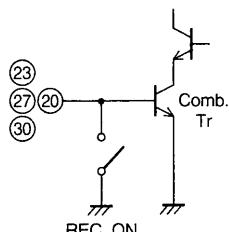
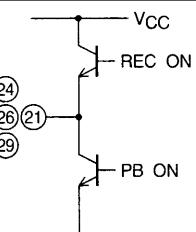
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Pin No.	Pin	Standard DC voltage (V)		Pin circuit	Notes
7	REC-H	PB	0		2.0 V
		REC	5		
8	ENV DET OUT	PB	Described in a separate document.		
		REC	0		
9	GND				
10	PB-OUT	PB	2.3		
		REC	3.6		
11	REC-Y-IN	REC	3.6		
12	AGC-FLT	PB	1.6		
		REC	1.6		
13	REC-CURRENT ADJ2	PB	2.5		4 V: +3.5 dB 2.5 V: ±0 dB (OPEN) 1 V: -6 dB
		REC	2.5		

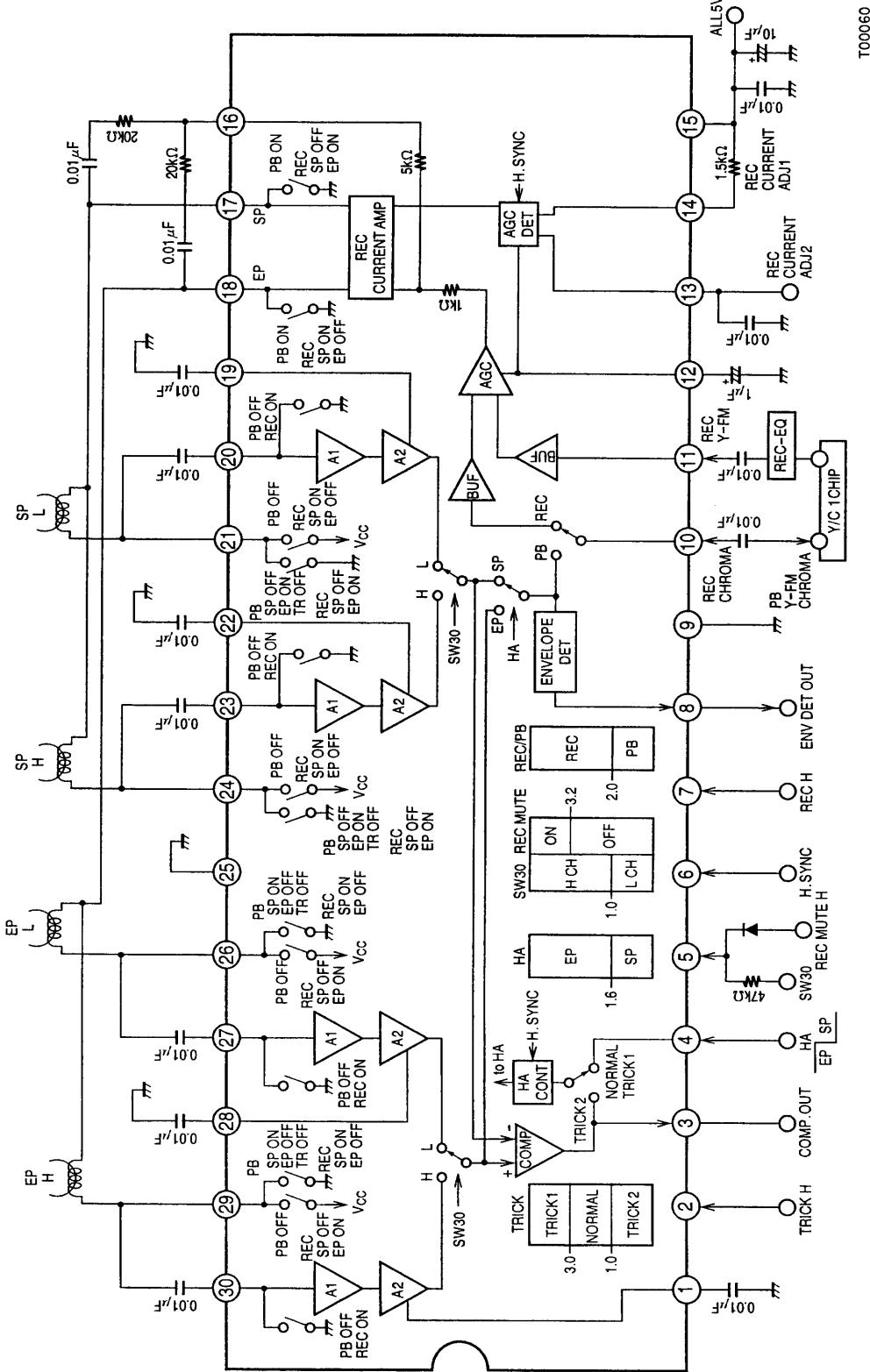
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Pin No.	Pin	Standard DC voltage (V)		Pin circuit	Notes
14	REC-CURRENT ADJ1	PB	4.5		
		REC	5.0		
15	V _{CC}				
16	REC-BIAS	PB	2.5		
		REC	1.7		
17	REC-SP OUT REC-EP OUT	PB	0		
18		REC	4.2		
20	SP-L-IN SP-H-IN EP-L-IN EP-H-IN	PB	0.7		
23					
27					
30		REC	0		
21	SP-L-SW SP-H-SW EP-L-SW EP-H-SW	PB	0		
24					
26					
29		REC	4.2		
25	PRE-GND				

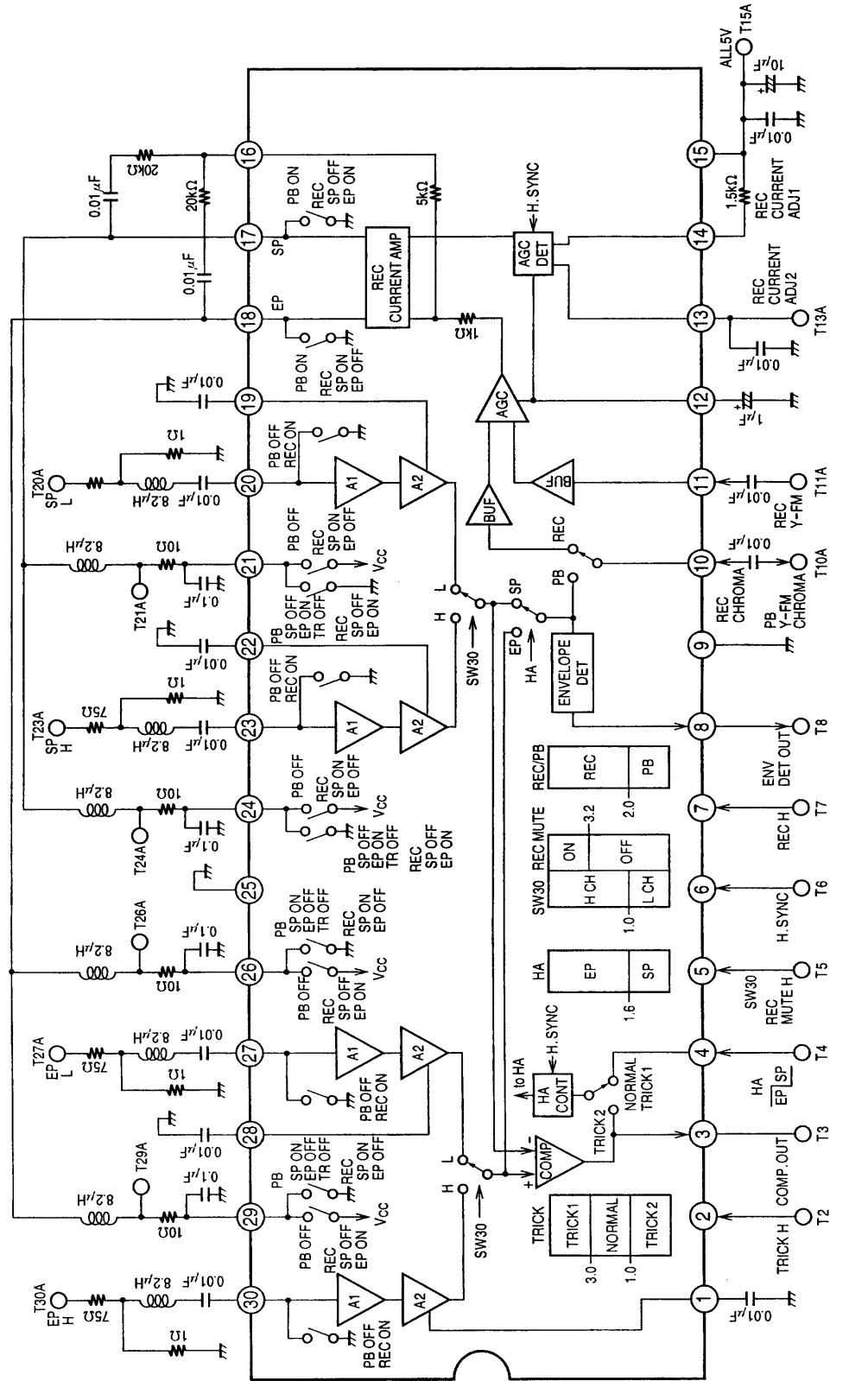
Block Diagram



T00060

LA7415

Test Circuit



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